Local-structure analysis around dopant atoms using multiple energy x-ray holography

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We used multiple energy x-ray holography (MEXH) to image the local atomic environment of Zn atoms doped in a GaAs wafer using synchrotron radiation and a multielement solid-state detector. The obtained atomic images revealed that the Zn atoms occupied substitutional site. By the comparison of the reconstructed images 1.41 Å above and below the emitter atom, the suppression of twin images due to MEXH was confirmed experimentally for certain atoms.

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I. INTRODUCTION

X-ray fluorescence holography (XFH) is a technique which can record the amplitude and phase of wavefronts scattered by atoms, relative to direct unscattered waves, and directly provide a three-dimensional atomic image of the environment around the atoms emitting the fluorescence. Two types of this method have been developed: “normal XFH” and “inverse XFH.” In normal XFH, fluorescence from atoms inside the sample approaching the detector on a direct path constitutes the holographic reference beam, and fluorescence scattered by neighboring atoms acts as the object beam. A holographic pattern can be recorded moving the detector around the sample. The inverse XFH is based on the idea of the optical reciprocity of the normal XFH and the application of known principles for x-ray standing waves. The multielement SSD is suitable for the inverse XFH of the impurity element, because it has a large detecting area and enables high countrate measurement.

II. EXPERIMENTAL DETAILS

The hologram measurement was carried out using synchrotron beam line BL10XU at SPring-8 in October 1999. SPring-8 (Super Photon ring-8 GeV) is one of the ultrahigh-brilliance synchrotron facilities in the world. The electron storage ring current was between 100 and 80 mA during measurements. The synchrotron radiation from an undulator was monochromatized by a Si (111) double-crystal monochromator. The GaAs:Zn wafer (001) was purchased from Furuuchi Chemical Co. (Tokyo, Japan). The Zn concentration in the wafer was determined to be 1.0×1019 atoms cm⁻³ (0.02 wt %) by a Hall measurement. The diameter and thickness of the sample were 50.0 and 0.25 mm, respectively. The incident x-ray energy was 9.7 and 10.0 keV, which was between the Zn and Ga K absorption edges, so as to avoid excitation of the Ga and As x-ray fluorescence.

Figure 1 shows a schematic illustration of the experimental setup. The sample was mounted on a two-axis (θ-φ) rotatable stage, where θ was the polar angle between the incident beam and the surface normal, and φ was the azimuthal angle between the [110] and the projection of the incident beam. The [110] direction of the sample was determined from the cleavage planes. Multielement SSD was placed parallel to the incident x-ray electric field, as shown in Fig. 1. The intensity of Zn Kα x-ray fluorescence was measured as a function of the azimuthal angle, φ, and polar angle, θ, within the ranges of 0° ≤ φ ≤ 360° and 26° ≤ θ ≤ 60°. The dwelling time for one pixel was 1 s with 2° steps in θ and 1° steps in φ. The total integrated intensity of the Zn Kα x-ray fluorescence at each pixel was about 200 000 counts.

III. RESULTS AND DISCUSSION

Since the raw hologram data were noisy, they were smoothed by applying low and high pass filters. The holo-
graphic patterns for the incident energies of 9.7 and 10.0 keV were different, while they showed periodical undulation reflecting the symmetry of the GaAs (001) plane. We reconstructed the atomic image from these holograms using the Barton algorithm,\textsuperscript{11} and successfully obtained the images of the first- and second-neighbor atoms around the emitter. But, the reconstructed atomic images were distorted and no more atoms could be observed.

In order to obtain clearer atomic images, we symmetrized the holograms by the use of the symmetry of the host GaAs single crystal.\textsuperscript{12} Figures 2(a) and 2(b) show twofold-averaged holographic patterns for 9.7 and 10.0 keV, respectively. From these holograms, we again reconstructed atomic images of planes parallel to the (001) lattice plane cutting through the Zn atom, and 1.41 Å (\(\equiv z/4\)) above and below the emitter atom, which are termed here planes A, B, and C.

Figures 3(a), 3(b), and 3(c) show the reconstructed images of planes A, B, and C. From Fig. 3(a), 110, 110, 110, and 110 atoms are clearly seen and the distances between the intensity maxima of these atoms and the emitter are equally 4.02 Å. The crystal structure of GaAs is a ZnS-like structure with \(a=5.65\) Å, that is, it consists of two face-centered-cubic cells. The Ga and As layers stack alternately along the c axis; these two layers are separated by 1.41 Å. The atomic configuration of the Ga layer is the same as that of the As layer, and the nearest Ga-Ga or As-As distances are 4.00 Å. Thus, the Zn atoms are found to substitute for a Ga or As site. This result well agreed with extended x-ray absorption fine structure (EXAFS) one.\textsuperscript{13} 200, 200, 020, 020 atoms are also visible at distances of 7.02 Å, which is 25% larger than the distance (5.65 Å) expected from the GaAs crystal structure.

In Fig. 3(b), strong \(\frac{1}{4}, \frac{1}{4}, \frac{1}{7}, \frac{1}{7}, \frac{1}{7}, \frac{1}{7}, \frac{1}{7}, \frac{1}{7}\) atoms and weak \(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}\) atoms are seen, revealing that Zn atoms are substituted selectively for one site of Ga or As. The possibility of As-site substitution may be negligible because of the charge neutrality. Figure 4 shows the possible model of the atomic arrangement around Zn atoms. Since the intensity of the x rays scattered from the atoms lying on plane B is stronger than those on plane C, it is considered that the \(\frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}, \frac{1}{4}\) atoms are the real image

FIG. 1. Experimental setup for MEXH measurement. The incident beam size was 0.25×0.25 mm\(^2\) and its intensity was monitored by an ionization chamber. X-ray fluorescence was detected by a 19 element solid-state detector. Angular acceptance of the detecting area was approximately 43\(^\circ\). The incident beam was linearly polarized and the electric field was parallel to the horizontal plane. The experiment was performed using the BL10XU beamline of SPring-8.

FIG. 2. (Color) Holograms of Zn in GaAs recorded at the incident energies of (a) 9.7 keV and (b) 10.0 keV. Hologram data \(\chi'(\theta, \phi)\) were twofold averaged using the relation \(\chi'(\theta, \phi) = [\chi(\theta, \phi) + \chi(\theta, \phi + 180\degree) + \chi(\theta, -\phi) + \chi(\theta, -\phi + 180\degree)]/4\), where \(\chi(\theta, \phi)\) was hologram data after applying the low and high pass filters. \(\chi'(\theta,\phi)\) was projected onto the \(k_x-k_y\) plane, where \(k_x = |k|\cos \phi \sin \theta, k_y = |k|\sin \phi \sin \theta\) and \(|k|\) is the wave vector magnitude of incident x rays.
FIG. 3. (Color) Holographic reconstruction of an environment around the Zn. The planes parallel to the (001) lattice plane cutting through the fluorescence emitter atom, 1.41 Å above and below the emitter atom are displayed in (a), (b), and (c), respectively. The dashed lines show the outline of the GaAs crystal cell. Solid and dotted circles show real and twin images, respectively.

and that $\frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}$ atomlike images are twin images of the $\frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}$ atoms existing on plane C, respectively. Holographic twin images appear necessarily in the image reconstructed from the single energy hologram and are suppressed by the reconstruction from the MEXH data. Twin image suppression becomes effective with an increase in the number of holograms recorded at different energies. However, since we measured only two holograms in our experiment, this effect is considered to be weak.

The $\frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}$ atomic images appearing in Fig. 3(c) are twin images of $\frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}$, atoms in Fig. 3(b), respectively. Since the intensity of each twin image nearly equaled that of the paired real image, the twin image suppression was not confirmed for these atoms.

In contrast, the real images of $\frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}, \frac{1}{2} + \frac{1}{2}$ atoms in Fig. 3(c) are obviously intensive compared to their twin images displayed in Fig. 3(b). This result revealed that two energy MEXH data contribute to suppressing the twin
image for $\frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}$ atoms. In addition to these, atomlike images are observed at $(x,y) = (\pm 2.6\,\text{Å}, \pm 2.6\,\text{Å})$ or $(\pm 5.2\,\text{Å}, \pm 5.2\,\text{Å})$ on plane $B$ and the intensities of their twin image on plane $C$ are also suppressed, but we could not assign them in this study.

The distances from the center to $\frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}$ atoms are equally 1.94 Å which well agreed with the distance (2.00 Å) predicted from the knowledge on the EXAFS and crystal data. While the distances from the center to $\frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}, \frac{1}{2}$ atoms are equally 5.13 Å, which is 14% shorter than the expected distance (6.00 Å). Taking into account the image of plane $A$, the atomic images of first- and second-neighbor atoms within the radius of 4 Å appear at accurate positions, while the positions of the other atomic images are largely displaced. It is considered that these large displacements originate from the weakness of the holographic signal from the atoms existing at the distance of over 4 Å from the emitter. This problem will be resolved by the increase of the total count in each pixel.

Beside imaging planes $A$, $B$, and $C$, the reconstruction was performed for the planes parallel to the $[001]$ lattice plane 2.83 Å ($=z/2$) above and below the plane $A$. The images existing on these planes were not visible, however, which was attributed to loss of image information along the $c$ axis as a direct consequence of the limited $k_z$ range of the measured hologram as well as the polarization effect of the incident beam. When the polarization vector was perpendicular to the polar rotation axis $\theta$, the horizontal atomic structure near the basal plane was emphasized and the vertical atomic structure near the $[001]$ axis was diminished. Images of these planes should become further resolved with full $2\pi$ scans used for the incident beams of the vertical and horizontal polarizations.

IV. CONCLUSIONS

We measured the hologram at two different energies using multielement SSD. Symmetrized holograms provide a clear atomic image around Zn, which revealed that most of the Zn atoms occupied the substitutional site in our GaAs wafer. Furthermore, twin image suppression due to the MEXH was recognized for certain atoms. The centrosymmetric atomic structure images reconstructed from single-energy holograms often diminish due to the real-twin image overlap problem. Therefore, the MEXH was predicted to be useful for the reconstruction of all near-neighboring atoms surrounding the emitter, and it was confirmed experimentally. Besides, the twin image suppression for non-centrosymmetric atomic structures is also important as demonstrated by Barton and Adams. However, it had not been confirmed experimentally as far as we know. Thus, we believe that this is experimental evidence. The present results demonstrate that the x-ray holography technique is applicable to practical structural analysis of trace impurities for a reasonable measurement time using a third-generation synchrotron radiation facility.

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